



TIP112

NPN SILICON TRANSISTOR

NPN EPITAXIAL SILICON DARLINGTON TRANSISTOR

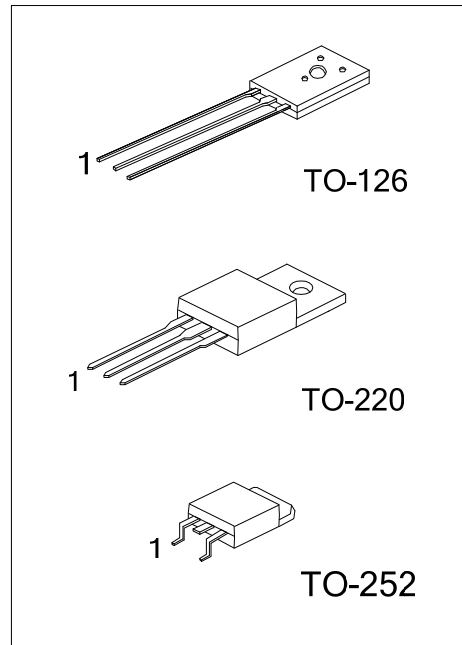
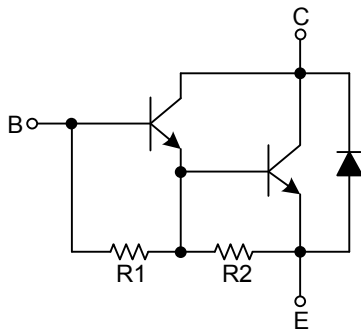
DESCRIPTION

The UTC **TIP112** is designed for such applications as: DC/DC converters supply line switching, battery charger, LCD backlighting, peripheral drivers, Driver in low supply voltage applications (e.g. lamps and LEDs) and inductive load driver (e.g. relays, buzzers and motors).

FEATURES

- * High DC current gain : $h_{FE} = 1000$ @ $V_{CE} = 4V, I_C = 1A$ (Min)
- * Low collector-emitter saturation voltage

EQUIVALENT TEST ($R_1 \approx 10k\Omega, R_2 \approx 0.6k\Omega$)



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
TIP112L-T60-K	TIP112G-T60-K	TO-126	E	C	B	Bulk
TIP112L-TA3-T	TIP112G-TA3-T	TO-220	B	C	E	Tube
TIP112L-TN3-R	TIP112G-TN3-R	TO-252	B	C	E	Tape Reel
TIP112L-TN3-T	TIP112G-TN3-T	TO-252	B	C	E	Tube

<p>TIP112L-T60-K</p> <p>(1) Packing Type (2) Package Type (3) Lead Free</p>	<p>(1) K: Bulk, T: Tube, R: Tape Reel (2) T60: TO-126, TA3: TO-220, TN3: TO-252 (3) G: Halogen Free, L: Lead Free</p>
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■ ABSOLUTE MAXIMUM RATING ($T_C = 25^\circ\text{C}$, unless otherwise specified)

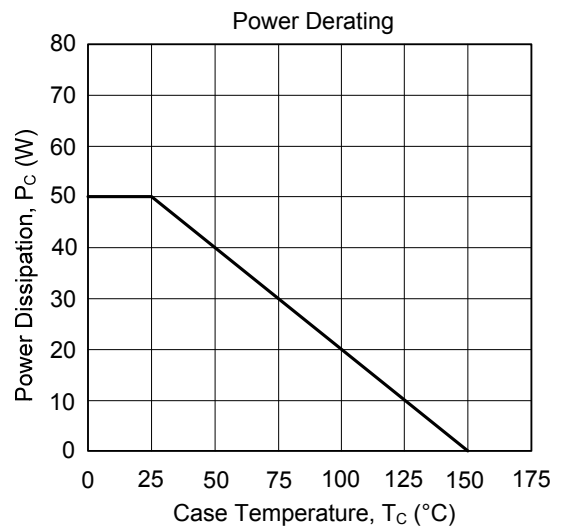
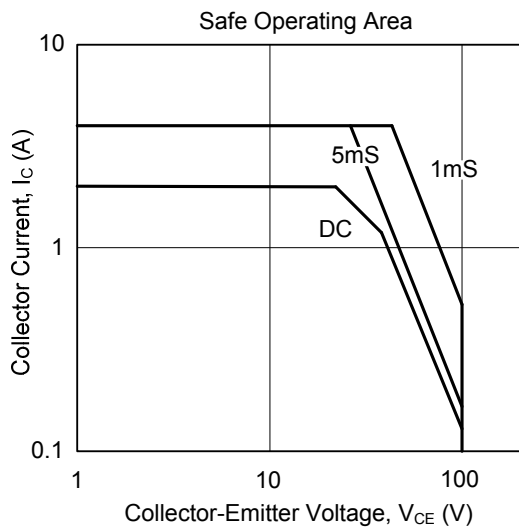
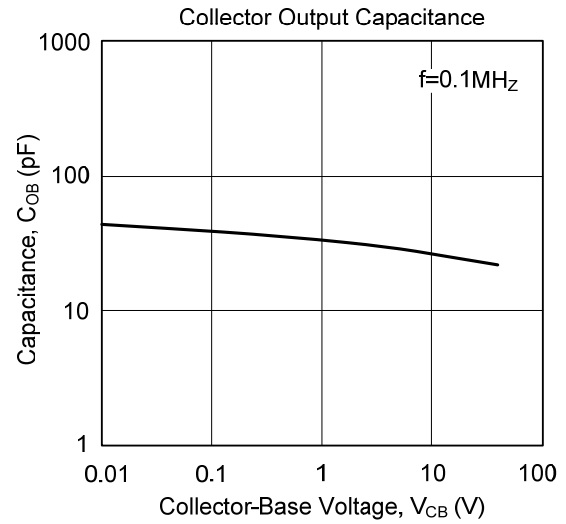
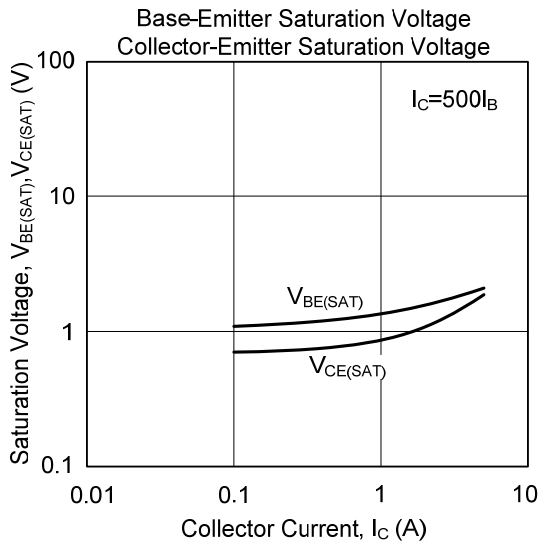
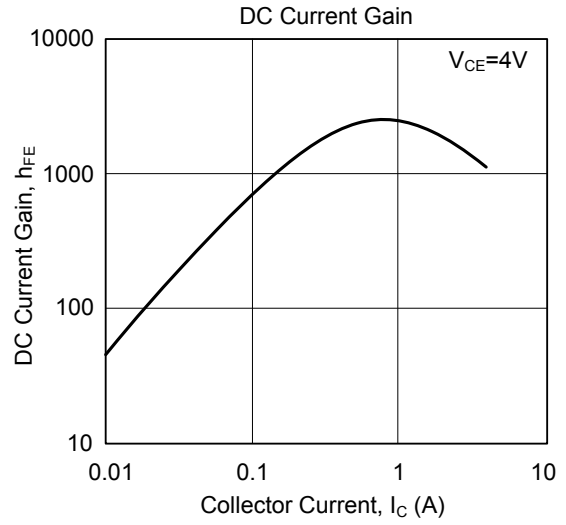
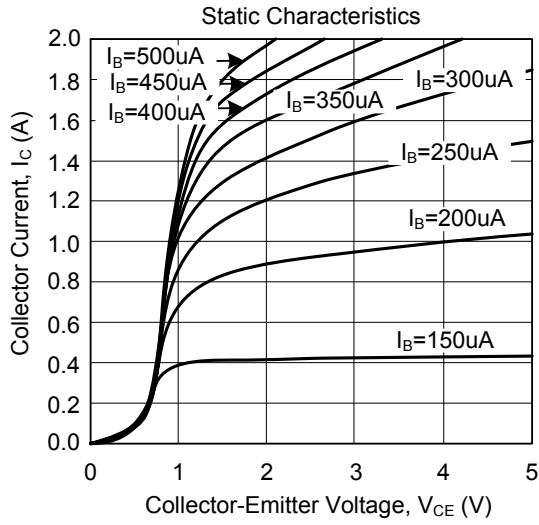
PARAMETER		SYMBOL	RATINGS	UNIT
Collector to Base Voltage		V_{CBO}	100	V
Collector to Emitter Voltage		V_{CEO}	100	V
Emitter to Base Voltage		V_{EBO}	5	V
Collector Current	DC	I_C	2	A
	Peak	I_{CM}	4	
Base Current (DC)		I_B	50	mA
Collector Dissipation	TO-126	P_C	10	W
	TO-220		40	
	TO-252		15	
Junction Temperature		T_J	150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-65~+150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	$V_{CEO(SUS)}$	$I_C=30\text{mA}, I_B=0\text{A}$	100			V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=2\text{A}, I_B=8\text{mA}$			2.5	V
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	$V_{CE}=4\text{V}, I_C=2\text{A}$			2.8	
Collector-Base Cut-Off Current	I_{CBO}	$V_{CB}=100\text{V}, I_E=0\text{A}$			1	mA
Collector-Emitter Cut-Off Current	I_{CEO}	$V_{CE}=50\text{V}, V_B=0\text{A}$			2	mA
Emitter-Base Cut-Off Current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0\text{A}$			2	mA
DC Current Gain	h_{FE}	$V_{CE}=4\text{V}, I_C=1\text{A}$	1000			
		$V_{CE}=4\text{V}, I_C=2\text{A}$	500			
Collector Capacitance	C_{OB}	$V_{CB}=10\text{V}, I_E=0\text{A}, f=0.1\text{MHz}$			100	pF

TYPICAL CHARACTERISTICS



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